

ASSP

# VOLTAGE DETECTOR

## MB3761

### VOLTAGE DETECTOR

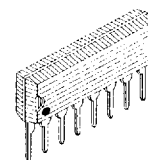
Designed for voltage detector applications, the Fujitsu MB3761 is a dual comparator with a built-in high precision reference voltage generator. Outputs are open-collector outputs and enable use of the OR-connection between both channels. Both channels have hysteresis control outputs. Because of a wide power supply voltage range and a low power supply current, the MB3761 is suitable for power supply monitors and battery backup systems.

- Wide power supply voltage range: 2.5 V to 40 V
- Low power and small voltage dependency supply current: 250  $\mu$ A typical.
- Built-in stable low voltage generator: 1.20 V typical.
- Easy-to-add hysteresis characteristics.
- Package: 8-pin Plastic SIP Package (Suffix: -PS)  
8-pin Plastic DIP Package (Suffix: -P)  
8-pin Plastic FPT Package (Suffix: -PF)

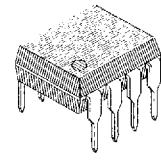
#### ABSOLUTE MAXIMUM RATINGS (See NOTE)

Rating	Symbol	Value	Unit
Power Supply Voltage	V <sub>CC</sub>	41	V
Output Voltage	V <sub>O</sub>	41	V
Output Current	I <sub>O</sub>	50	mA
Input Voltage	V <sub>IN</sub>	-0.3 to +6.5	V
Power Dissipation	P <sub>D</sub>	350 (T <sub>A</sub> $\leq$ 70°C)	mW
Storage Temperature	T <sub>STG</sub>	-55 to 125	°C

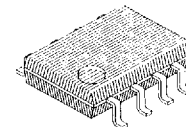
**NOTE:** Permanent device damage may occur if **ABSOLUTE MAXIMUM RATINGS** are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



PLASTIC PACKAGE  
SIP-08P-M03



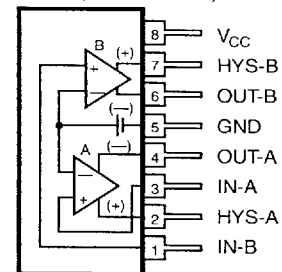
PLASTIC PACKAGE  
DIP-08P-M01



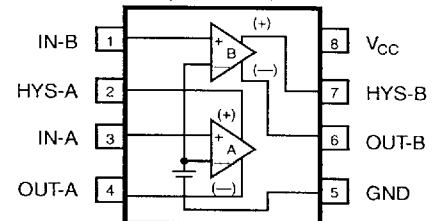
PLASTIC PACKAGE  
FPT-08P-M01

#### PIN ASSIGNMENT

(FRONT VIEW)

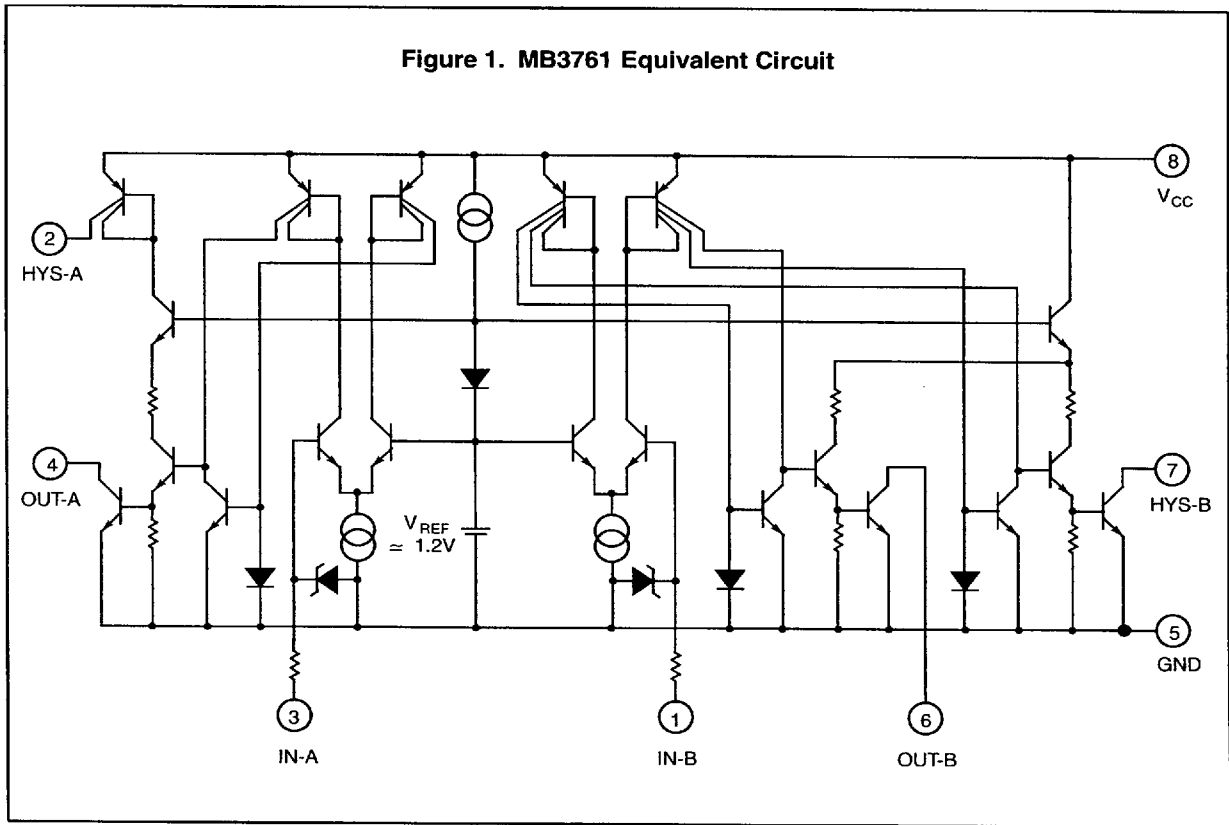


(TOP VIEW)



This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

# MB3761



## ■ RECOMMENDED OPERATING CONDITIONS

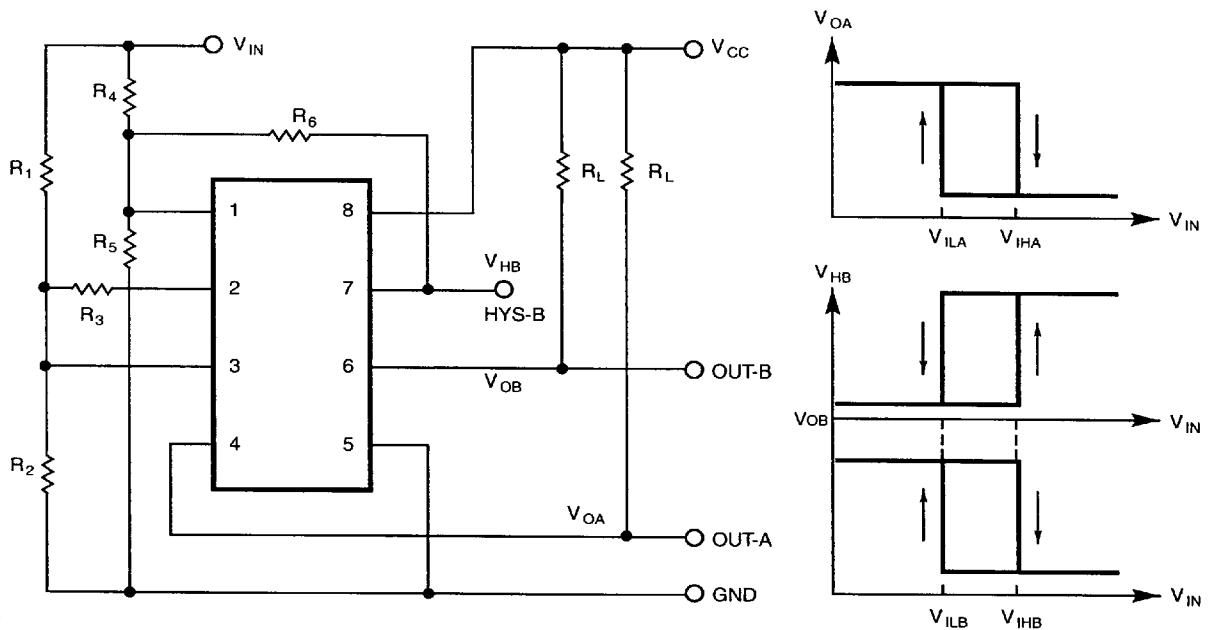
Parameter	Symbol	Value	Unit
Power Supply Voltage	VCC	2.5 to 40	V
Operating Temperature	TA	-20 to 75	°C
Output Current at pin 4	IO4	4.5	mA
Output Current at pin 6	IO6	3.0	mA

## ■ ELECTRICAL CHARACTERISTICS

T<sub>A</sub>=25°C, V<sub>CC</sub>=5V

Parameter	Designator	Conditions	Values			Unit
			Min	Typ	Max	
Power Supply Voltage	ICCL	V <sub>CC</sub> =40 V, V <sub>IL</sub> =1.0 V	-	250	400	μA
	ICCH	V <sub>CC</sub> =40 V, V <sub>IH</sub> =1.5 V	-	400	600	μA
Threshold Voltage	V <sub>TH</sub>	I <sub>O</sub> =2 mA, V <sub>O</sub> =1 V	1.15	1.20	1.25	V
Deviation of Threshold Voltage	ΔV <sub>TH1</sub>	2.5 V ≤ V <sub>CC</sub> ≤ 5.5 V	-	3	12	mV
	ΔV <sub>TH2</sub>	4.5 V ≤ V <sub>CC</sub> ≤ 40 V	-	10	40	mV
Offset Voltage between Outputs	VOOSA	I <sub>OA</sub> = 4.5 mA, V <sub>OA</sub> =2 V I <sub>HA</sub> = 20 mA, V <sub>HA</sub> =3 V	-	2.0	-	mV
	VOSSB	I <sub>OB</sub> =3 mA, V <sub>OB</sub> =2 V I <sub>HB</sub> =3 mA, V <sub>HB</sub> =2 V	-	2.0	-	mV
Temperature Coefficient of Threshold Voltage	α	-20°C ≤ T <sub>A</sub> ≤ 70°C	-	±0.05	-	mV/°C
Difference Voltage on Threshold Voltage between Channel	ΔV <sub>THAB</sub>		-10	-	-10	mV
Input Current	I <sub>IL</sub>	V <sub>IL</sub> =1.0 V	-	5		nA
	I <sub>IH</sub>	V <sub>IH</sub> =1.5 V	-	100	500	nA
Output Leakage Current	I <sub>OH</sub>	V <sub>O</sub> =40 V, V <sub>IL</sub> =1.0 V	-	-	1	μA
Hysteresis Output Leakage Current	I <sub>HLA</sub>	V <sub>CC</sub> =40 V, V <sub>HA</sub> =0 V, V <sub>IL</sub> =1.0 V	-	-	0.1	μA
	I <sub>HHB</sub>	V <sub>HB</sub> =40 V, V <sub>IH</sub> =1.5 V	-	-	1	μA
Output Sink Current	I <sub>OLA</sub>	V <sub>O</sub> =1.0 V, V <sub>IH</sub> =1.5 V	6	12	-	mA
	I <sub>OLB</sub>	V <sub>O</sub> =1.0 V, V <sub>IH</sub> =1.5 V	4	10	-	mA
Hysteresis Current	I <sub>HHA</sub>	V <sub>H</sub> =0 V, V <sub>IH</sub> =1.5 V	40	80	-	μA
	I <sub>HLB</sub>	V <sub>H</sub> =1.0 V, V <sub>IL</sub> =1.0 V	4	10	-	mA
Output Saturation Voltage	V <sub>OLA</sub>	I <sub>O</sub> = 4.5 mA, V <sub>IH</sub> =1.5 V	-	120	400	mV
	V <sub>OLB</sub>	I <sub>O</sub> = 3.0 mA, V <sub>IH</sub> =1.5 V	-	120	400	mV
Hysteresis Saturation	V <sub>HHA</sub>	I <sub>H</sub> = 20 μA, V <sub>IH</sub> =1.5 V	-	50	200	mV
	V <sub>HLB</sub>	I <sub>H</sub> = 3.0 mA, V <sub>IL</sub> =1.0 V	-	120	400	mV
Output Delay Time	t <sub>PHL</sub>	R <sub>L</sub> =5 KΩ	-	2	-	μs
	t <sub>PLH</sub>	R <sub>L</sub> =5 KΩ	-	3	-	μs

Figure 2. Operational Definitions



$$V_{IHA} = \left(1 + \frac{R_1}{R_2}\right) V_R$$

$$V_{ILA} = \left(1 + \frac{R_1}{R_2 \parallel R_3}\right) V_R - \frac{R_1}{R_3} V_{CC}$$

$$V_{IHB} = \left(1 + \frac{R_4}{R_5 \parallel R_6}\right) V_R$$

$$V_{ILB} = \left(1 + \frac{R_4}{R_5}\right) V_R$$

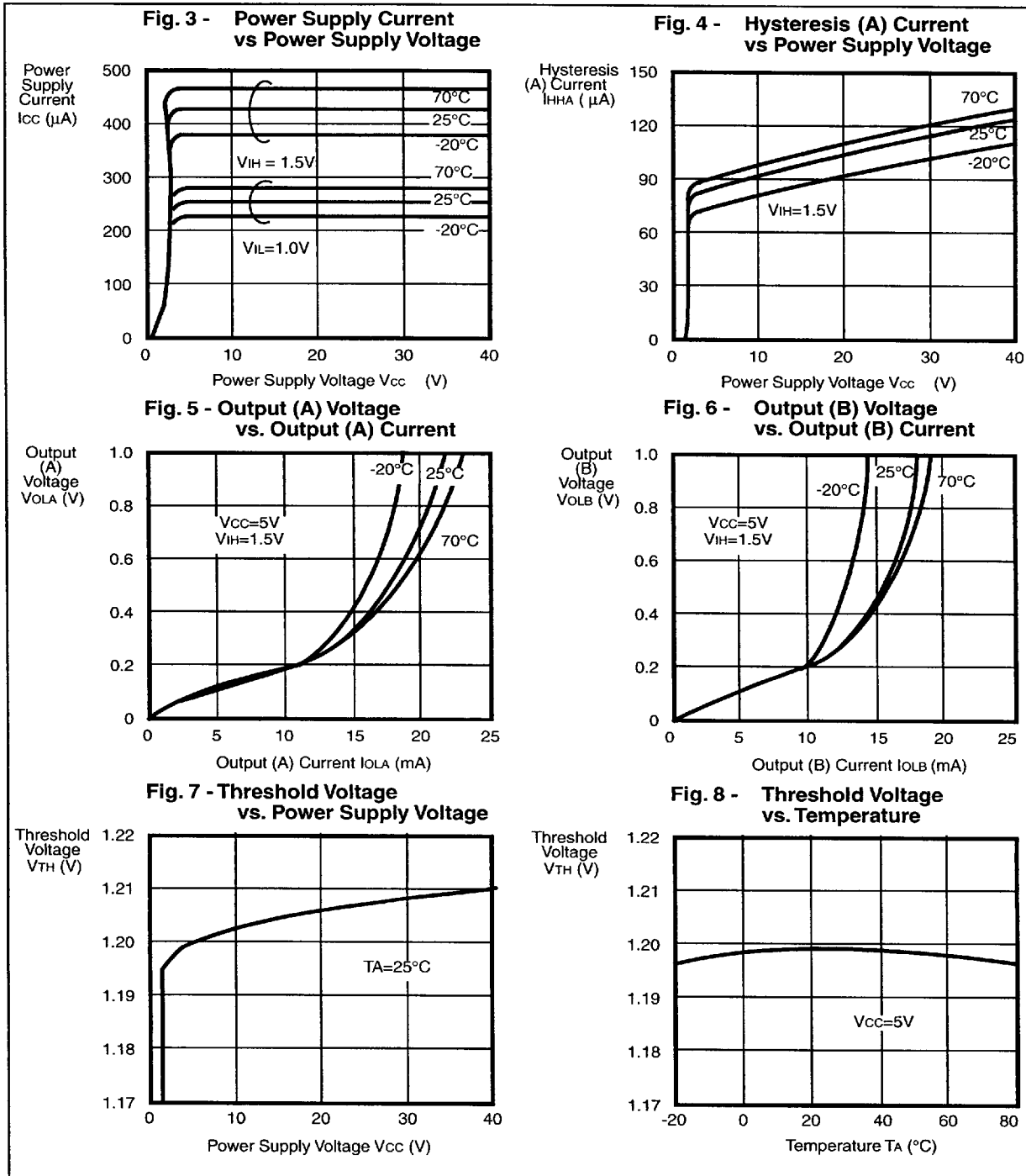
NOTE)

$$V_R \approx V_{TH} (\approx 1.20V)$$

$$R_2 \parallel R_3 = \frac{R_2 R_3}{R_2 + R_3}$$

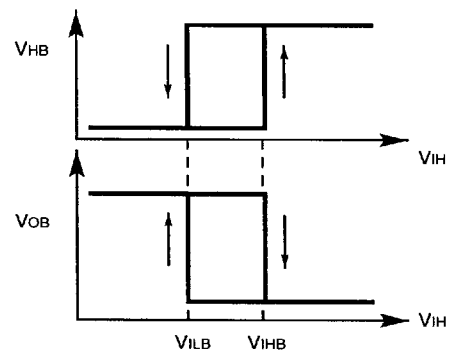
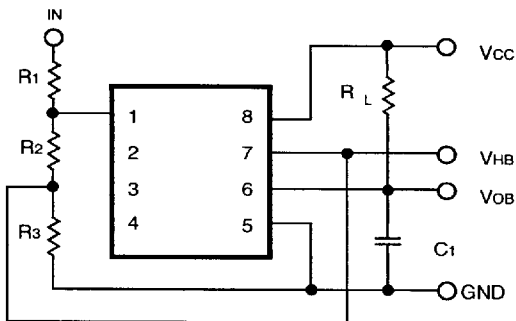
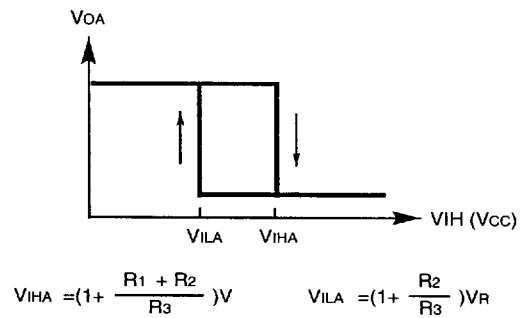
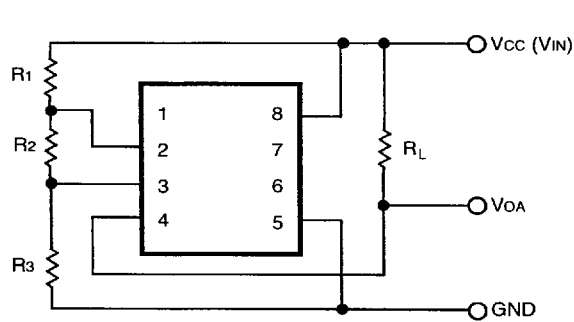
$$R_5 \parallel R_6 = \frac{R_5 R_6}{R_5 + R_6}$$

■ TYPICAL PERFORMANCE CHARACTERISTICS



## APPLICATION EXAMPLES

Figure 9. Addition of Hysteresis



Note: All calculations occur with the output voltage at 0. The hysteresis values are adjusted for load condition and saturation voltage.

$$V_{IHB} = \left(1 + \frac{R_1}{R_2}\right) V_R$$

$$V_{ILB} = \left(1 + \frac{R_1}{R_2 + R_3}\right) V_R$$

■ APPLICATION EXAMPLES (Continued)

Figure 10. Voltage Detection for Alarm

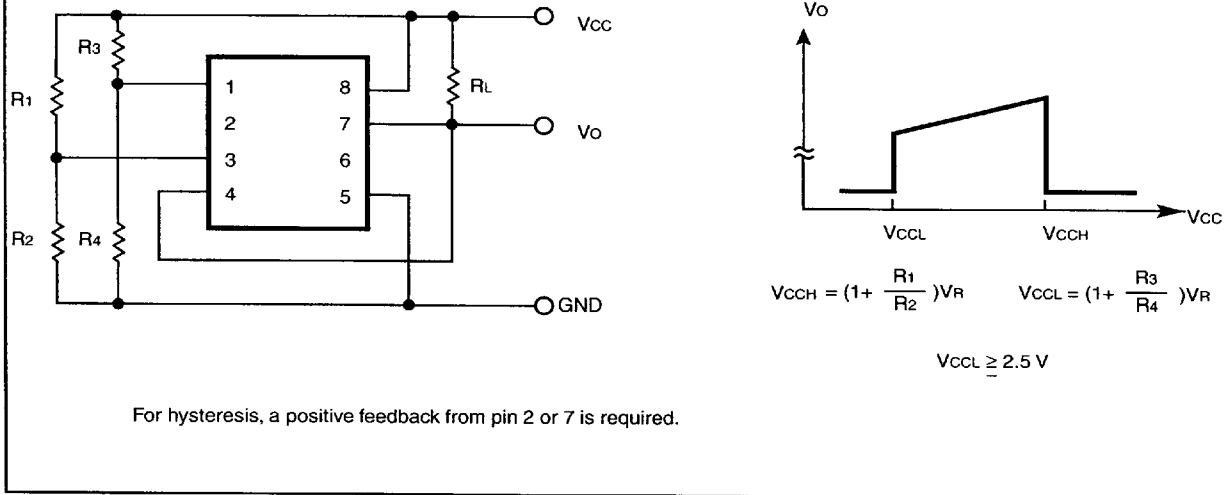
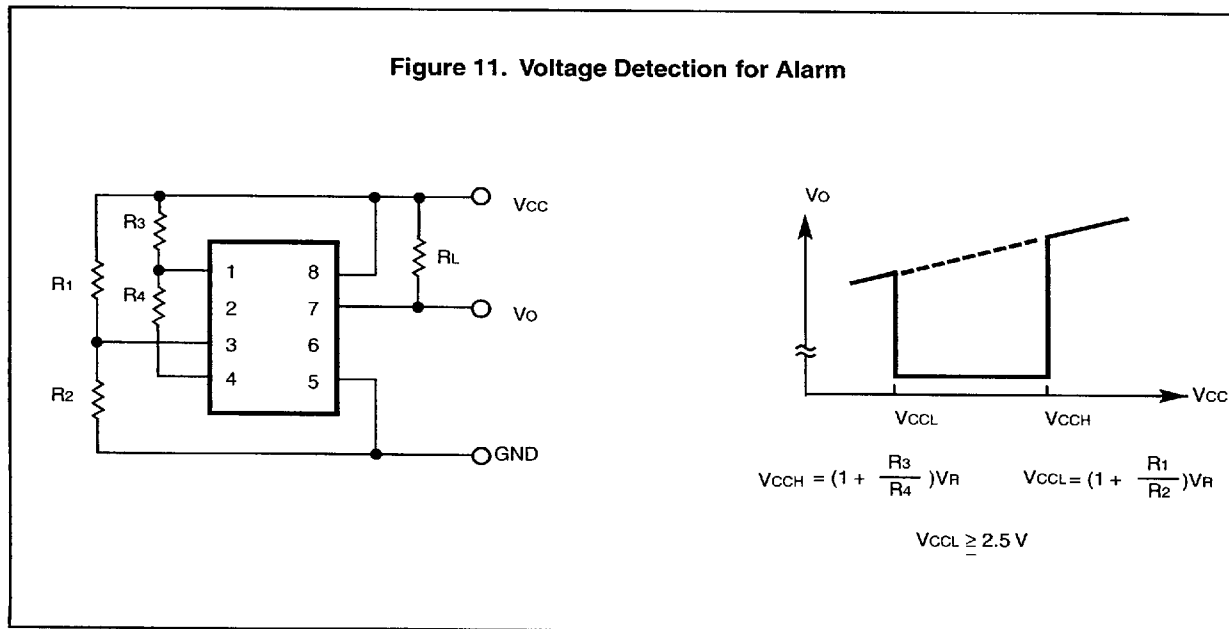
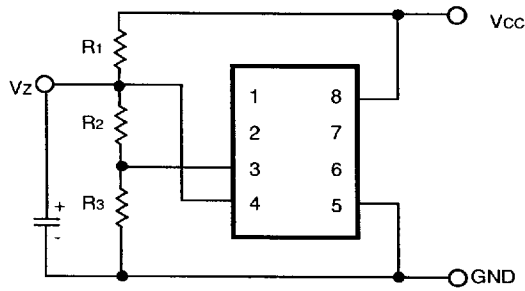


Figure 11. Voltage Detection for Alarm



## ■ APPLICATION EXAMPLES (Continued)

Figure 12. Programmable Zener

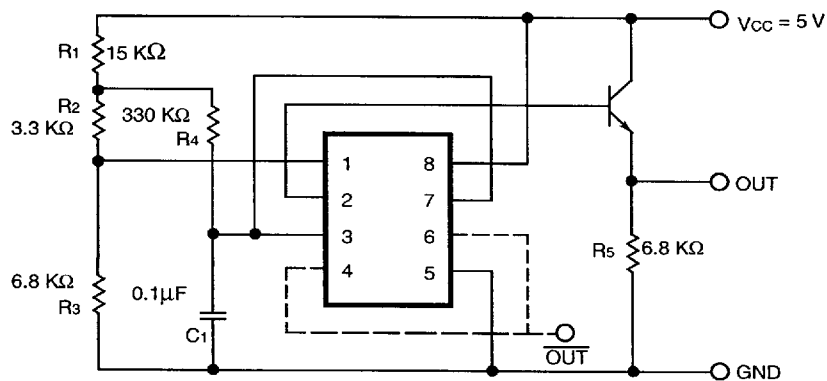


$$V_Z = \left(1 + \frac{R_2}{R_3}\right) V_R$$

$$\frac{V_Z}{R_2 + R_3} \leq \frac{V_{CC} - V_Z}{R_1} \leq 6\text{mA}$$

Channel B can be used independently.

Figure 13. Recovery Reset Circuit



■ PACKAGE DIMENSIONS

Figure 14. DC Characteristics

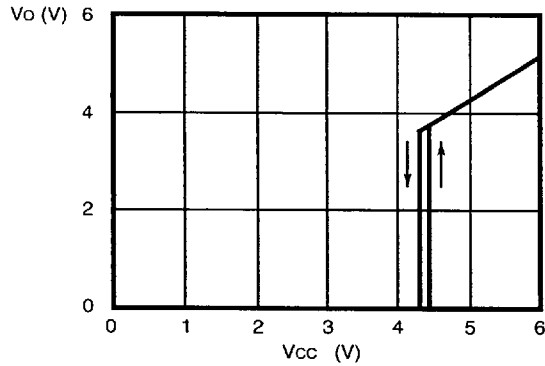
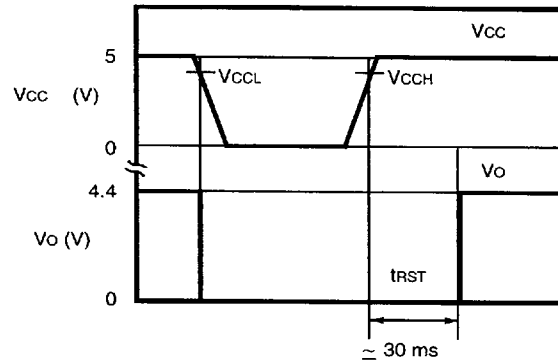


Figure 15. Response Characteristics



- Voltage Threshold Levels ( $V_{CCL}$  and  $V_{CCH}$ ) and Hysteresis Width can be changed by the resistors ( $R_1$  through  $R_4$ ).

$$V_{CCL} = \frac{R_1 + R_2 + R_3}{R_3} V_{TH}$$

$$V_{CCH} = V_{CCL} + \frac{R_1 (R_2 + R_3)}{R_3 R_4} V_{TH}$$

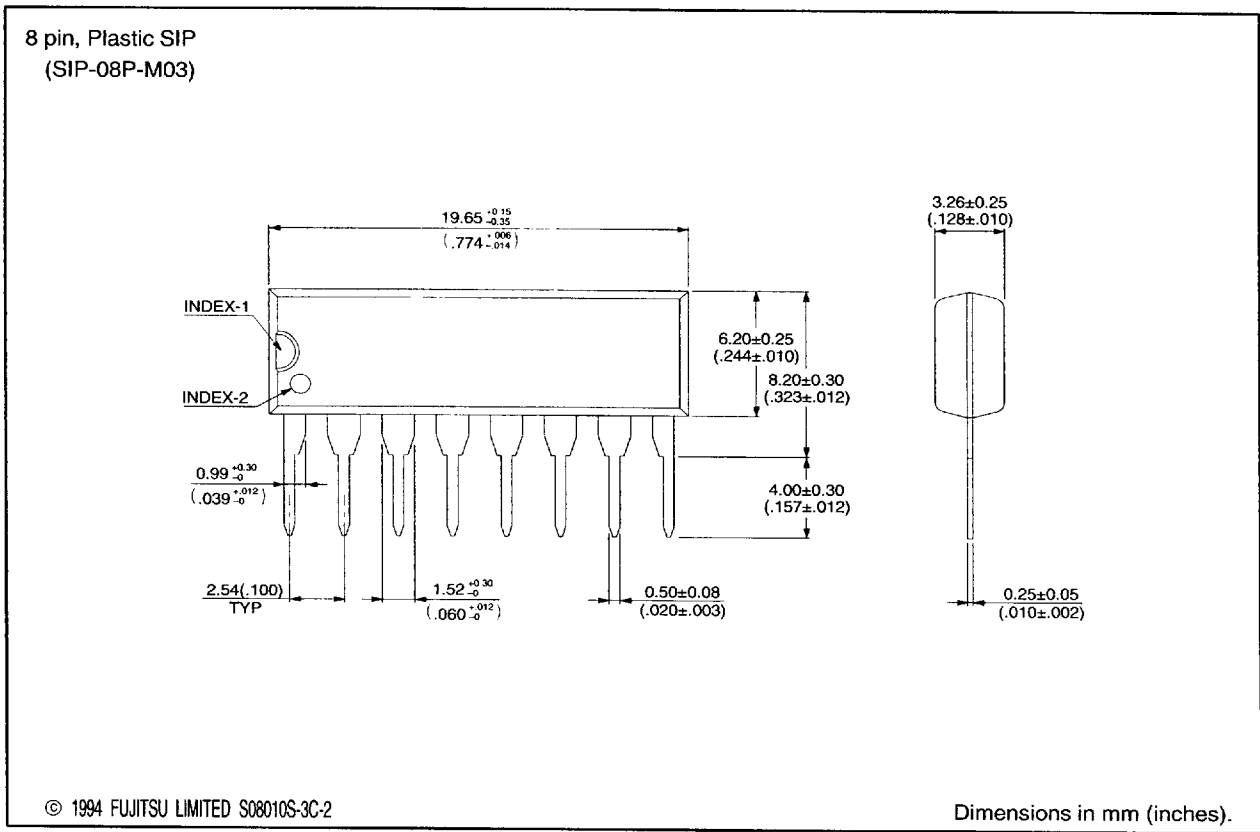
- Power-On Reset Time is provided by the following approximate equation:

$$t_{RST} = -C_1 R_4 \cdot \ln \left\{ 1 - \frac{V_{TH}}{V_{CC}} \left( 1 + \frac{R_1}{R_2 + R_3} \right) \right\}$$

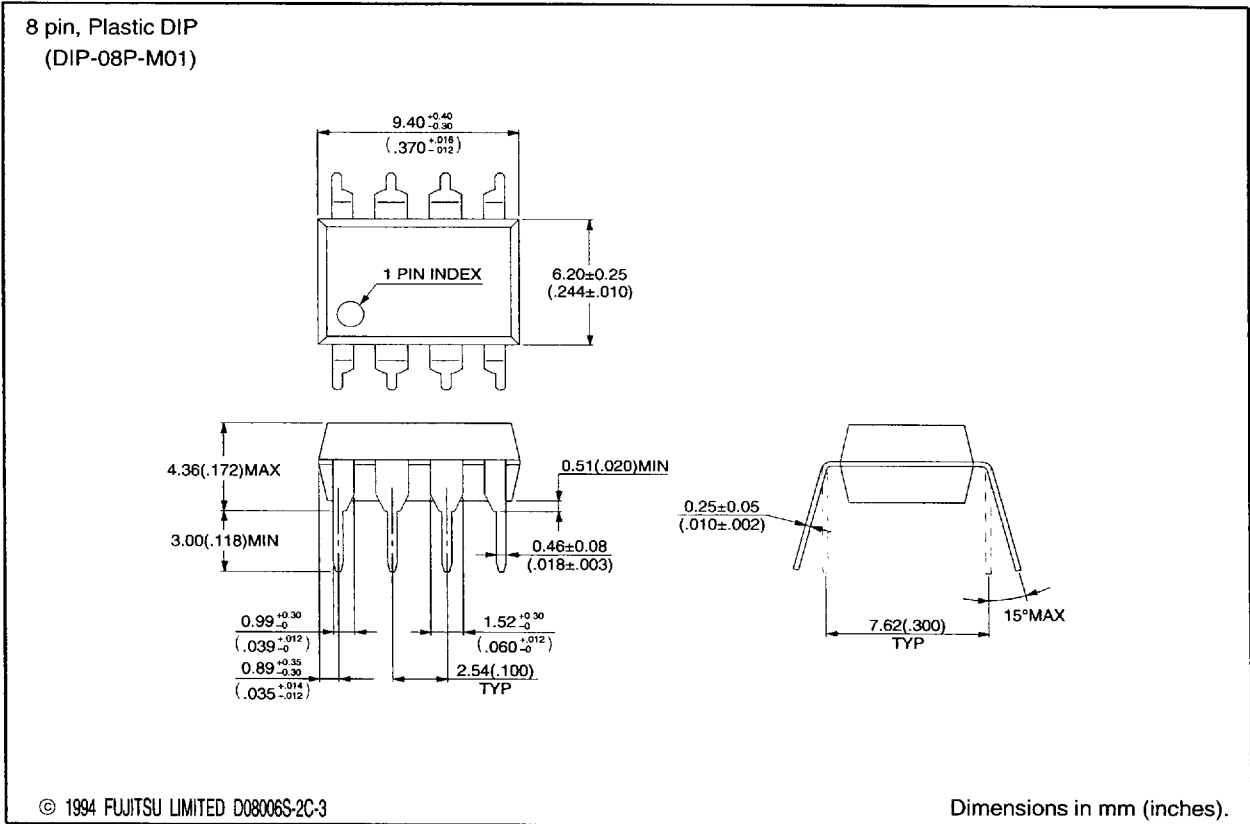
- The recommended value of hFE of the external transistor is from 50 to 200.
- In the case of an instant power fail, the remaining charge in  $C_1$  effects  $t_{RST}$ .
- If necessary, the reversed output is provided on HYS terminal

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## ■ PACKAGE DIMENSIONS (Continued)



■ PACKAGE DIMENSIONS (Continued)

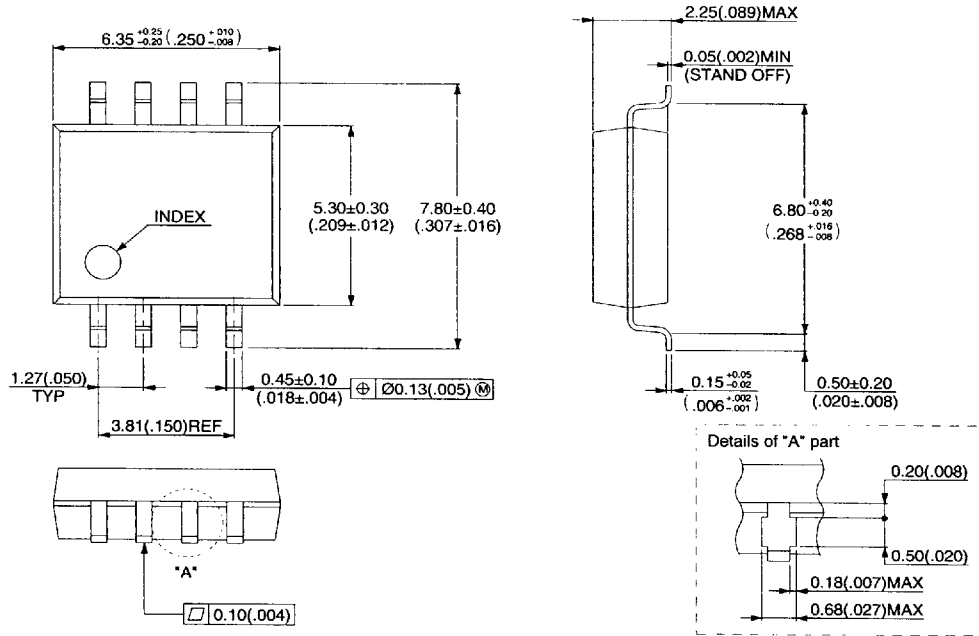


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## ■ PACKAGE DIMENSIONS (Continued)

8 pin, Plastic SOP  
(FPT-08P-M01)



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Dimensions in mm(inches).